## NSN 5962-01-372-5964

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-372-5964

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|--|
| Body Length:   |
| Between 1.470 inches and 1.490 inches  |
| Body Width:  |
| Between 0.590 inches and 0.610 inches  |
| Body Height:   |
| Between 0.212 inches and 0.232 inches  |
| Operating Tempurature Range:   |
| -55.0/+125.0 degrees celsius   |
| Storage Tempurature Range:   |
| -65.0/+150.0 degrees celsius   |
| End Application:   |
| Milstar  |
| Features Provided:   |
| Electrostatic sensitive and radiation hardened and programmed and ultraviolet erasable and w/enable                        |
| Inclosure Material:  |
| Ceramic  |
| Inclosure Configuration:   |
| Dual-in-line Dual-in-line  |
| Output Logic Form:   |
| Metal oxide-semiconductor logic  |
| Input Circuit Pattern:   |
| 17 input   |
| Criticality Code Justification:  |
| Feat   |
| Case Outline Source And Designator:  |
| D-10 mil-m-38510   |
| Terminal Surface Treatment:  |
| Solder   |
| Product Name:  |
| Microcircuit, programmed read only memory (mdm tdbb)   |
| Voltage Rating And Type Per Characteristic:  |
| -0.6 volts power source and 6.25 volts power source  |
| Memory Device Type:  |
| Eprom  |
| Special Features:  |
| Electrostatic discharge sens/hardness critical; altered item, programmed device is sv258-0084-010 cage 95105 checksum 918c |
| Nuclear Hardness Critical Feature:   |
| Hardened   |
|  |

**Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

28 printed circuit

## NSN 5962-01-372-5964

Memory Microcircuit - Page 2 of 2



Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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